

Physics 460/560 Lecture 5

Quantum Transport

We have seen that the conditions for the validity of Ohm's law $R = \rho \frac{L_x}{A}$ are that the dimensions of the specimen $L_x, L_y, L_z \gg l, \lambda$.

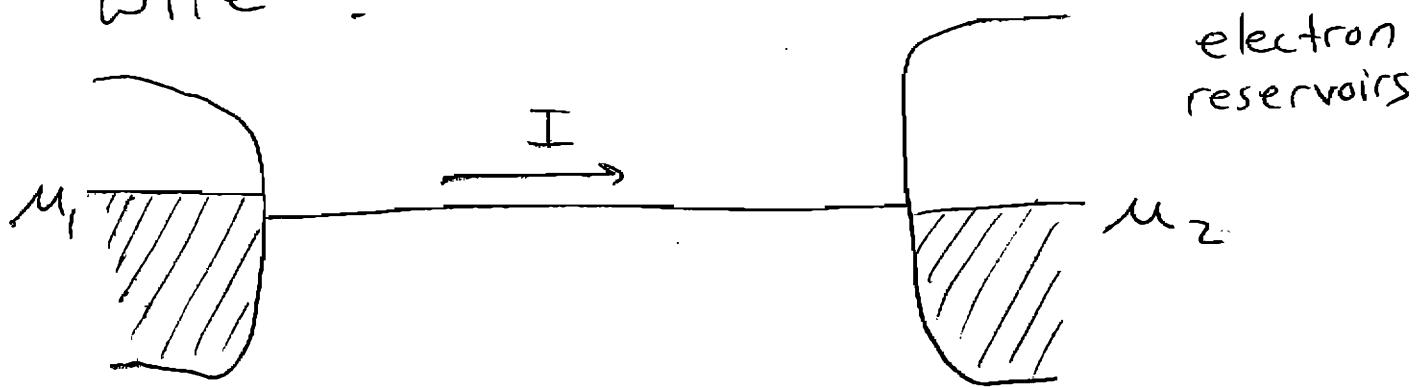
$L_i \gg l$ is necessary in order to be able to define a coarse grained distribution $f(\vec{r}, \vec{p}, t)$ which varies across the specimen.

$L_i \gg \lambda$ is necessary because the Boltzmann equation neglects wave-mechanical effects. The opposite limit $L_i \ll l$, $L_i \sim \lambda$ is the extreme quantum limit of ballistic

transport.

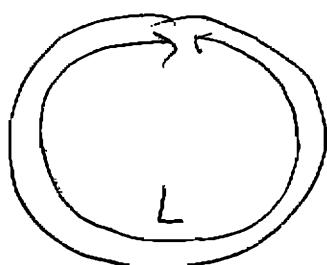
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Q: What is the resistance
of a perfect one-dimensional
wire?



$$I = e v_F \frac{\partial n}{\partial E} (\mu_1 - \mu_2)$$

$\frac{\partial n}{\partial E}$ = density of states per unit length (unidirectional)



$$\psi(x) = A e^{ikx}$$

$$\psi(x+L) = \psi(x) \Rightarrow e^{ikL} = 1$$

$$k = \frac{2\pi N}{L}, \quad N \in \mathbb{Z}$$

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$$\frac{\partial n}{\partial E} = \frac{\partial (N/L)}{\partial k} \frac{1}{\frac{\partial E}{\partial k}}$$

$$= \frac{1}{2\pi} \frac{1}{\hbar v_F} = \frac{1}{\hbar v_F}$$

$$I = \frac{e}{h} (V_1 - V_2) = \frac{e^2}{h} V$$

$$V = IR$$

$$R = \frac{h}{e^2}$$

$$\frac{h}{e^2} = 25,812.8 \Omega$$

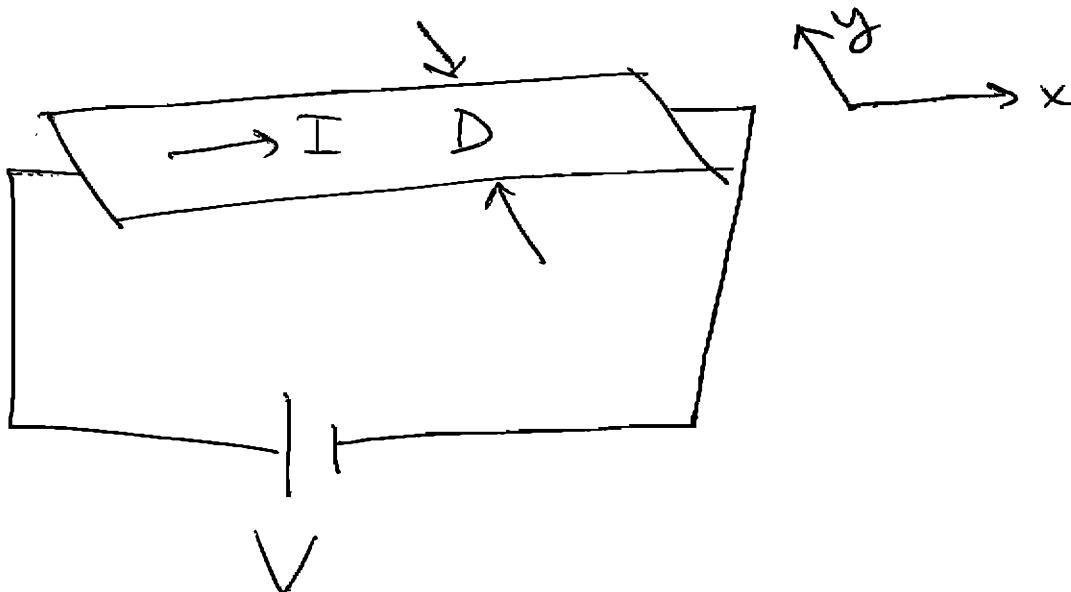
sometimes this unit of resistance
 is known as the "von Klitzing," after
 the Nobel laureate who first measured
 it accurately in ca. 1980.

Contrary to the expectation

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of ohm's law, R is independent
of the length of the wire!

Q: What is the resistance
of a perfect two-dimensional
wire of width D ?



S

Schrödinger's equation:

$$-\frac{\hbar^2}{2m} \left(\frac{\partial^2}{\partial x^2} + \frac{\partial^2}{\partial y^2} \right) \Psi(x, y) = E \Psi(x, y)$$

Boundary conditions:

$$\Psi(x, 0) = \overline{f(x, D)} = 0$$

Separation of variables:

$$\widehat{\Psi}(x, y) = \psi(x) \phi(y)$$

$$\frac{1}{4} \frac{d^2 \psi}{dx^2} + \frac{1}{\phi} \frac{d^2 \phi}{dy^2} = -\frac{2mE}{\hbar^2}$$

$$\psi(x) = e^{ikx}$$

$$-\frac{\hbar^2}{2m} \frac{d^2 \phi}{dy^2} = \left(E - \frac{\hbar^2 k^2}{2m} \right) \phi$$

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Solution:

$$\phi(y) = A \sin(p y)$$

$$p^2 = \frac{2mE}{\hbar^2} - k^2$$

$$\text{B.C.: } \sin pD = 0$$

$$pD = n\pi \quad p = \frac{n\pi}{D}$$

$$E = \frac{\hbar^2 k^2}{2m} + \frac{\hbar^2 \pi^2 n^2}{2m D^2}$$

$$E = \frac{\hbar^2 k^2}{2m} + E_n$$

How many transverse states
are there with $E_n < \epsilon_F$?

$$\frac{\hbar^2 \pi^2 N^2}{2m D^2} \leq \frac{\hbar^2 k_F^2}{2m}$$

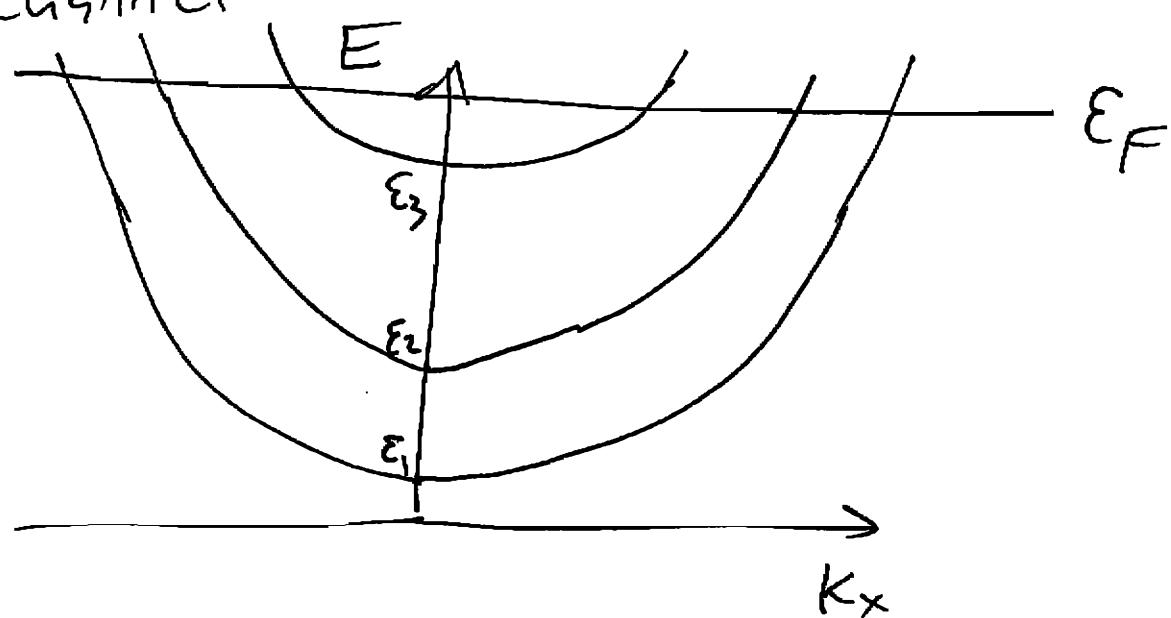
Z

$$n \leq \frac{k_F D}{\pi}$$

$$N = \max\{n\} = \text{Int}\left\{\frac{k_F D}{\pi}\right\}$$

of modes grows roughly proportional to D. Each mode n acts as a one-dimensional

channel:



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$$I = \frac{Ne^2}{h} V$$

$$R = \frac{h}{Ne^2} \quad G = R^{-1} = \frac{Ne^2}{h}$$

Landauer formula

In general, if the quantum mechanical probability for an electron in channel n to traverse the wire is T_n , the conductance is

$$G = \frac{e^2}{h} \sum_n T_n .$$

Conductance Quantization

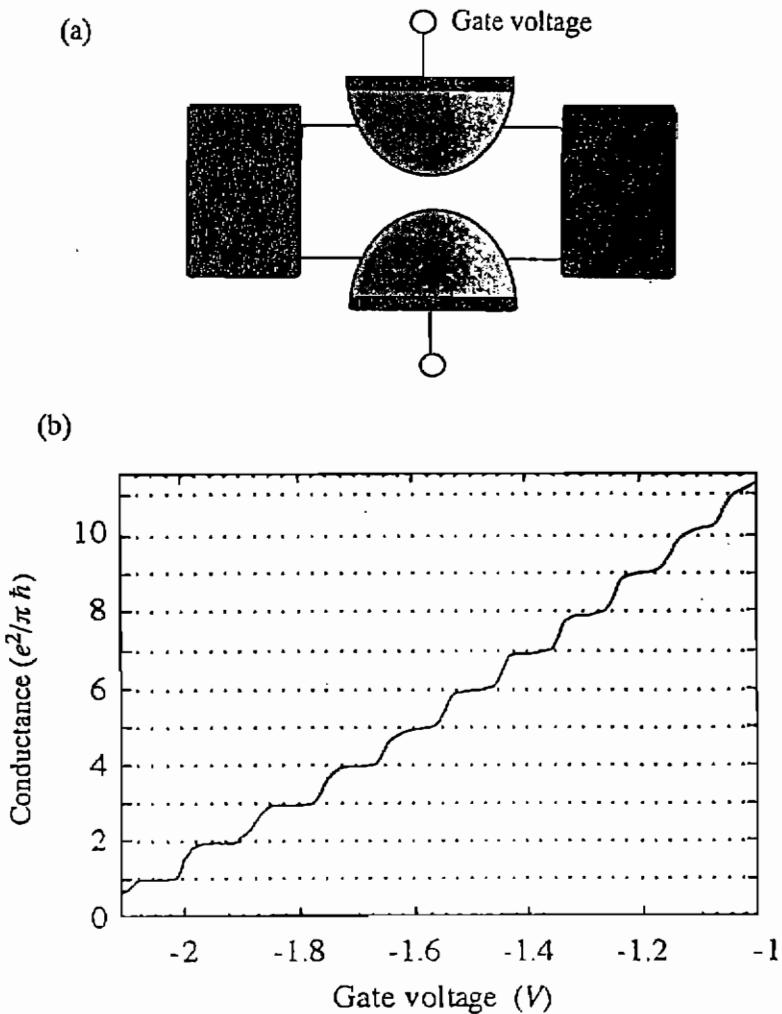


Fig. 2.1.2. Quantized conductance of a ballistic waveguide. (a) A negative voltage on a pair of metallic gates (called the split-gate configuration) is used to deplete and narrow down the constriction progressively. (b) Measured conductance vs. gate voltage. The measured resistance also includes a series resistance due to the wide regions connecting the constriction to the contacts. This series resistance is measured separately by removing the negative voltage on the gates and is subtracted off before plotting. Reproduced with permission from B. J. van Wees *et al.* (1988), *Phys. Rev. Lett.*, **60**, 848. Similar results were reported simultaneously by D. Wharam *et al.* (1988), *J. Phys. C*, **21**, L209.

Q: What is the resistance
 of a perfect 3-D wire with
 a square cross section $D^2 = A$? 10

$$E = \frac{\hbar k^2}{2m} + \frac{\hbar^2 \pi^2 (n^2 + m^2)}{2mA}$$

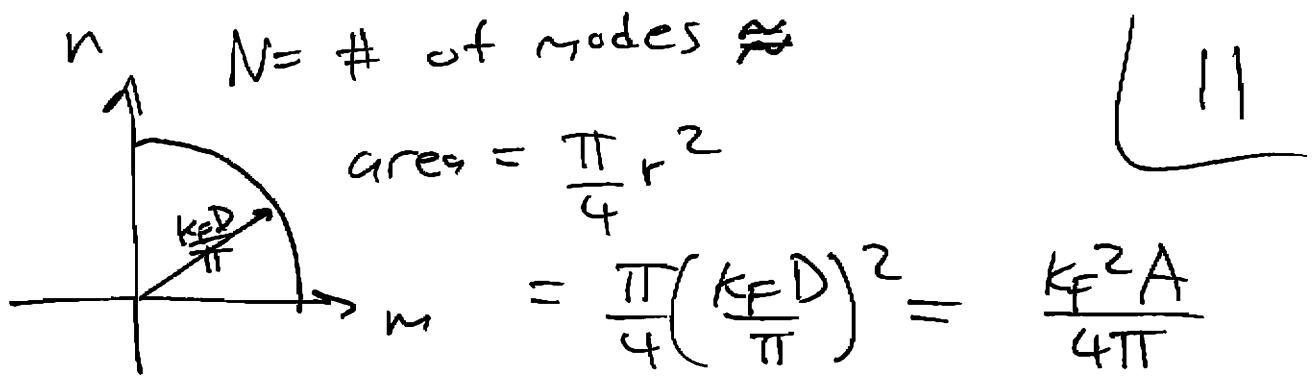
of nodes with $E_{nm} < E_F$?

$$E_{nm} = \frac{\hbar^2 \pi^2 (n^2 + m^2)}{2mA}$$

$$\frac{\hbar^2 \pi^2 (n^2 + m^2)}{2mA} < \frac{\hbar^2 k_F^2}{2m}$$

$$n^2 + m^2 < \frac{k_F^2 A}{\pi^2}$$

$$\sqrt{n^2 + m^2} < \frac{k_F D}{\pi}$$



$$G = N \frac{e^2}{h} \approx \frac{k_F^2 A}{4\pi} \frac{e^2}{h}$$

If $\vec{B} = 0$, and charge carriers have spin- $\frac{1}{2}$, we must multiply G by 2:

$$G \approx \frac{2e^2}{h} \frac{k_F^2 A}{4\pi} \quad \text{(Shravins formula)}$$

Like Ohm's law, $G \propto A$;
unlike Ohm's law, G indep.
of L !

mode

$$\epsilon \frac{2\pi A}{\pi^2 t^2}$$

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1 1

2

1 2

5

2 1

5

2 2

8

1 3

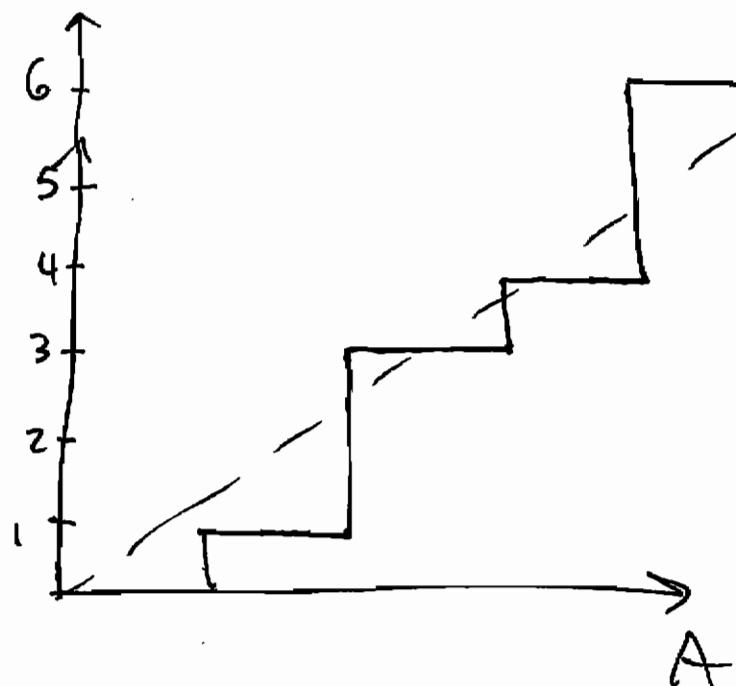
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3 1

10

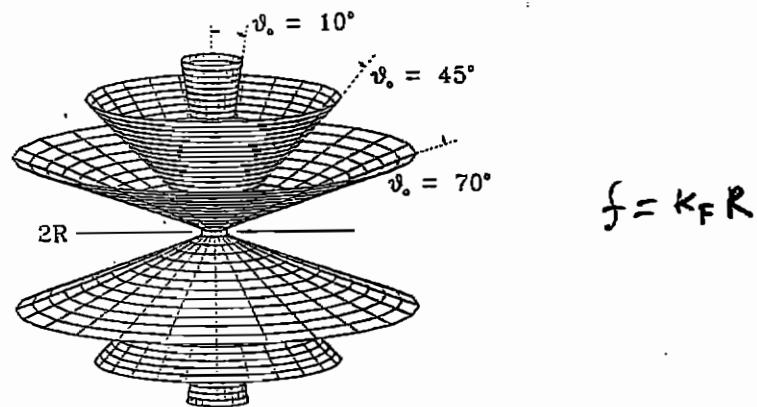
$$\frac{G}{\frac{2e^2}{h}}$$

Shorin
formulas



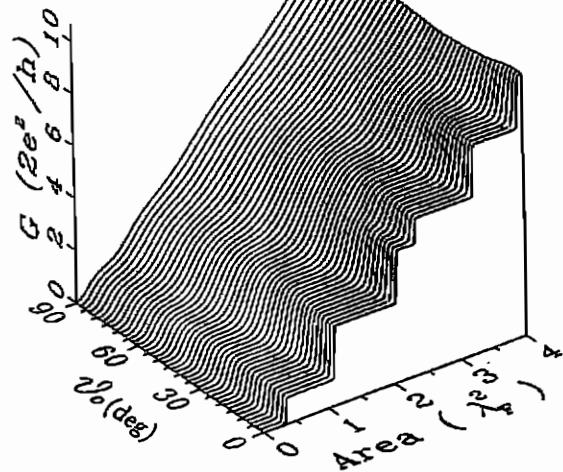
Calculation for hyperbolic constriction

[Torres, Pascual, and Sáenz, PRB 49, 16581 (1994)]

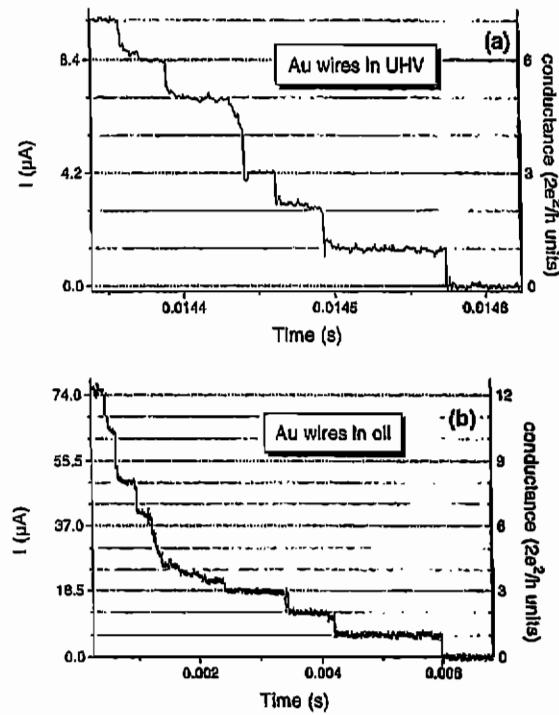
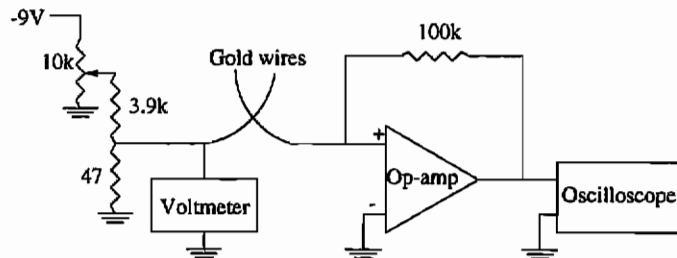


$$T_{vv'} = \frac{\delta_{vv'}}{1 + \exp\left(\frac{\pi}{f} [\epsilon_v - m^2 - f^2 + 1/4]\right)}$$

$$G = \frac{2e^2}{h} \sum_{vv'} T_{vv'}$$



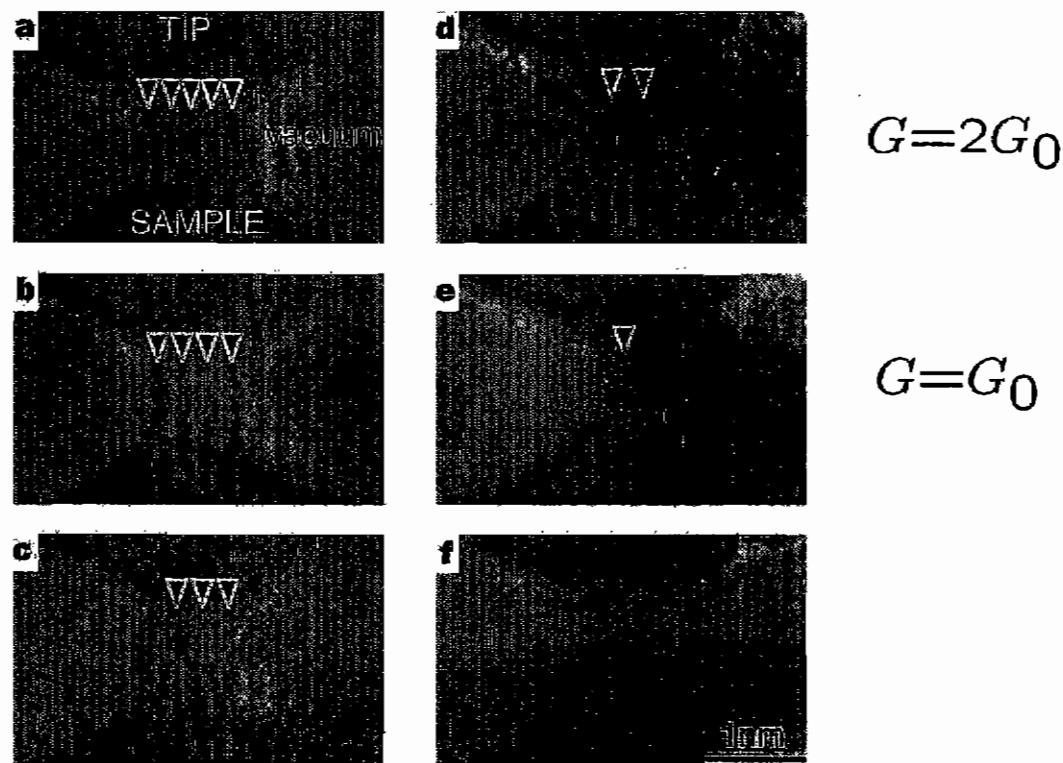
Spontaneously occurring nanocontacts



J. L. Costa-Krämer *et al.*, Surf. Sci. **342**, L1144 (1995)

E. L. Foley *et al.*, Am. J. Phys. **67**, 389 (1999)

Electron microscope video of an atomic-scale gold contact breaking

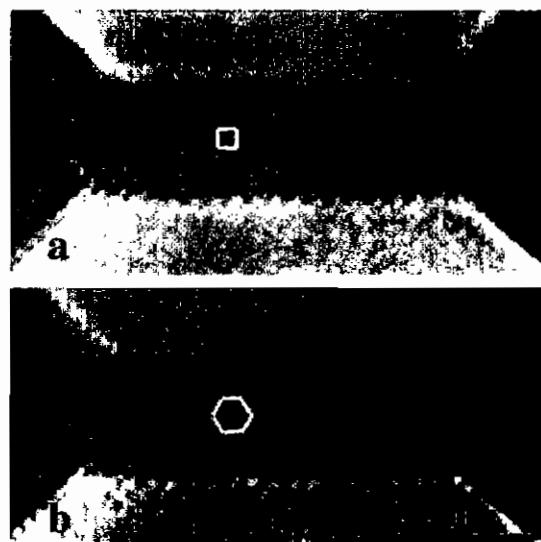


H. Ohnishi *et al.*, Nature 395, 780 (1998)

Gold nanobridges



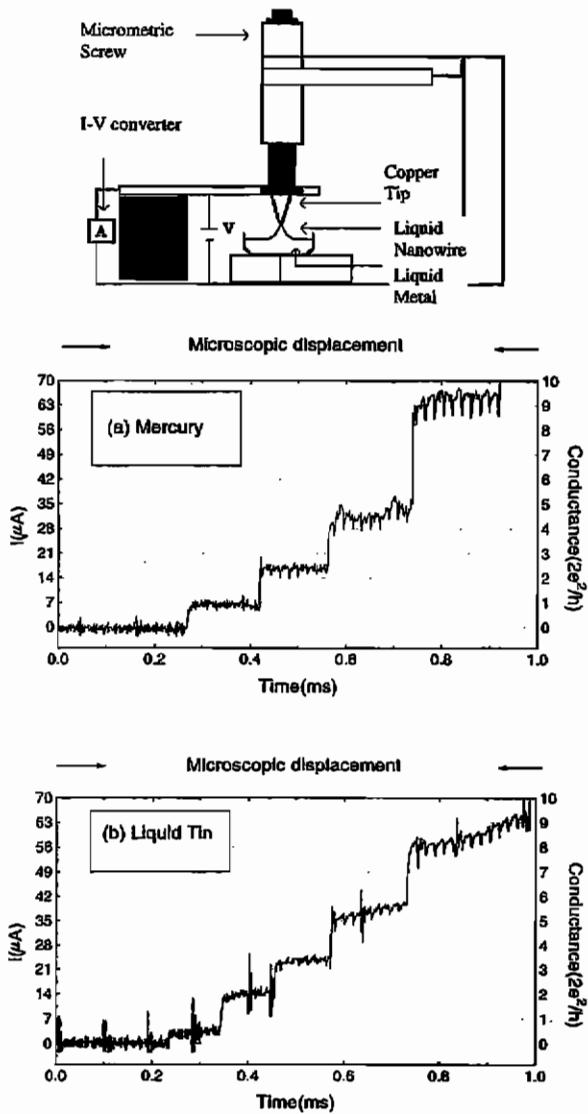
Amorphous



Crystalline

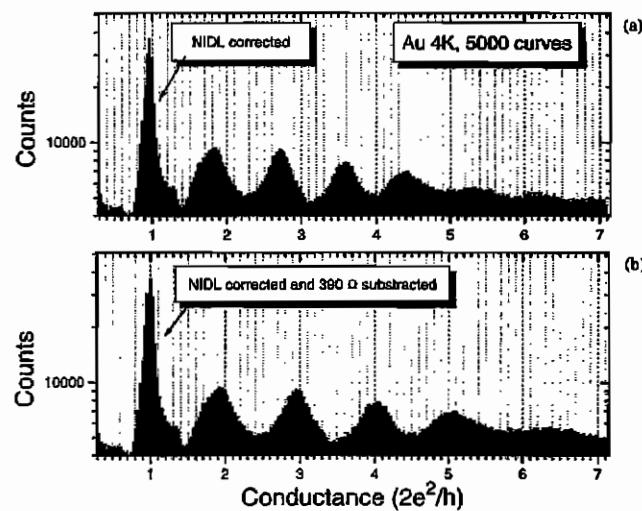
Y. Kondo & K. Takayanagi, PRL 79, 3455 (1997)

Liquid metal nanowires

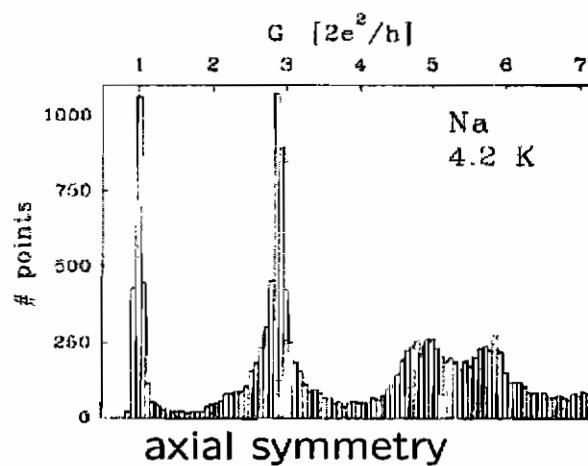


J. L. Costa-Krämer *et al.*, PRB 55, 5416 (1997)

Conductance histograms



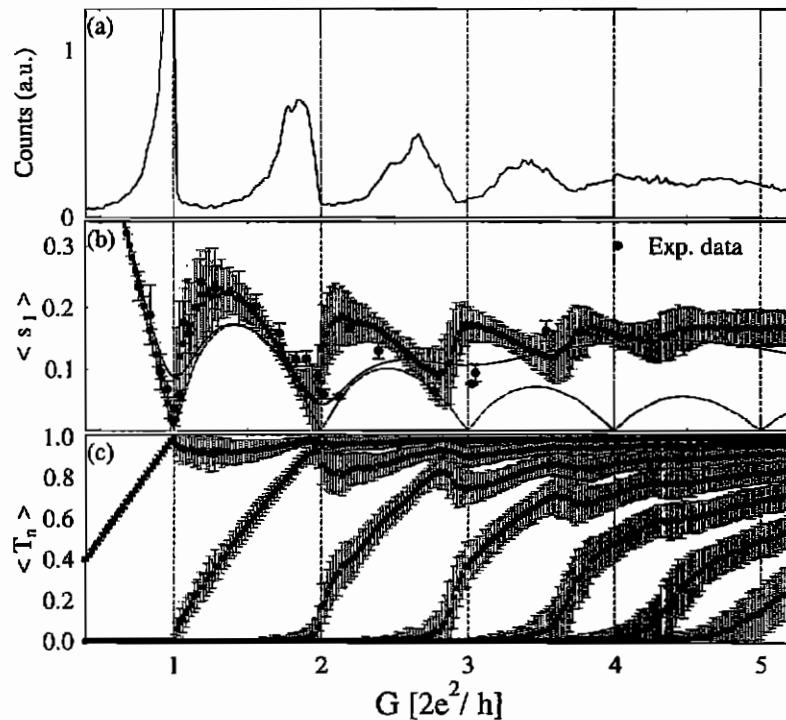
J. L. Costa-Krämer *et al.*, PRB 55, 12910 (1997)



J. M. Krans *et al.*, Nature 375, 767 (1995)

Quantum reduction of shot noise

$$s_I = \frac{P_I}{2eI} = \frac{\sum_n T_n(1 - T_n)}{\sum_n T_n}$$



Exp: van den Brom & van Ruitenbeek, PRL 82, 1526 (1999)

Theory: J. Bürgi & CAS, PRL 83, 3342 (1999)